

Joint QUASAR and THz Group Workshop on  
Accelerator Science and Technology

9 September 2009

# Beam Loss Monitoring with Optical Fibers for Particle Accelerators

Angela Intermite

[www.quasar-group.org](http://www.quasar-group.org)



- Introduction to beam loss monitoring:
  - *goals*
  - *requirements*
- Beam loss monitoring by optical fibers
- Working principle of the composite sensor
- Parameters of Cerenkov effect in optical fibers
- SiPM structure
- SiPM response
- Outlook

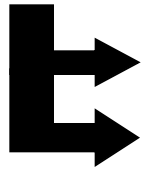




# How to select a beam loss monitor: goals and parameters

## Goals

- Measure losses



Regular losses

Irregular losses

Radiation damages

- Localize losses

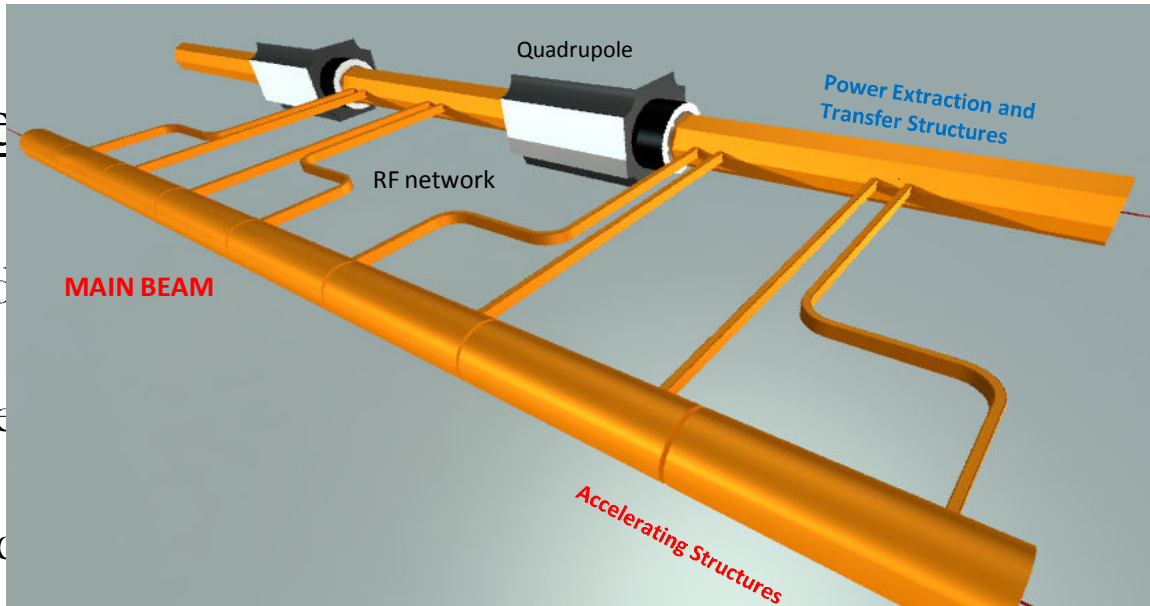
## Parameters

- Sensitivity
- Ease of calibration
- Radiation hardness
- Reliability
- Costs (incl. Electronics)
- Physical size
- Localization of beam losses

# Optical Fiber Beam Loss Monitor

## Advantages

- Distributed
- Small dimensions
- Smart structures
- Immune to magnetic fields
- Radiation resistant



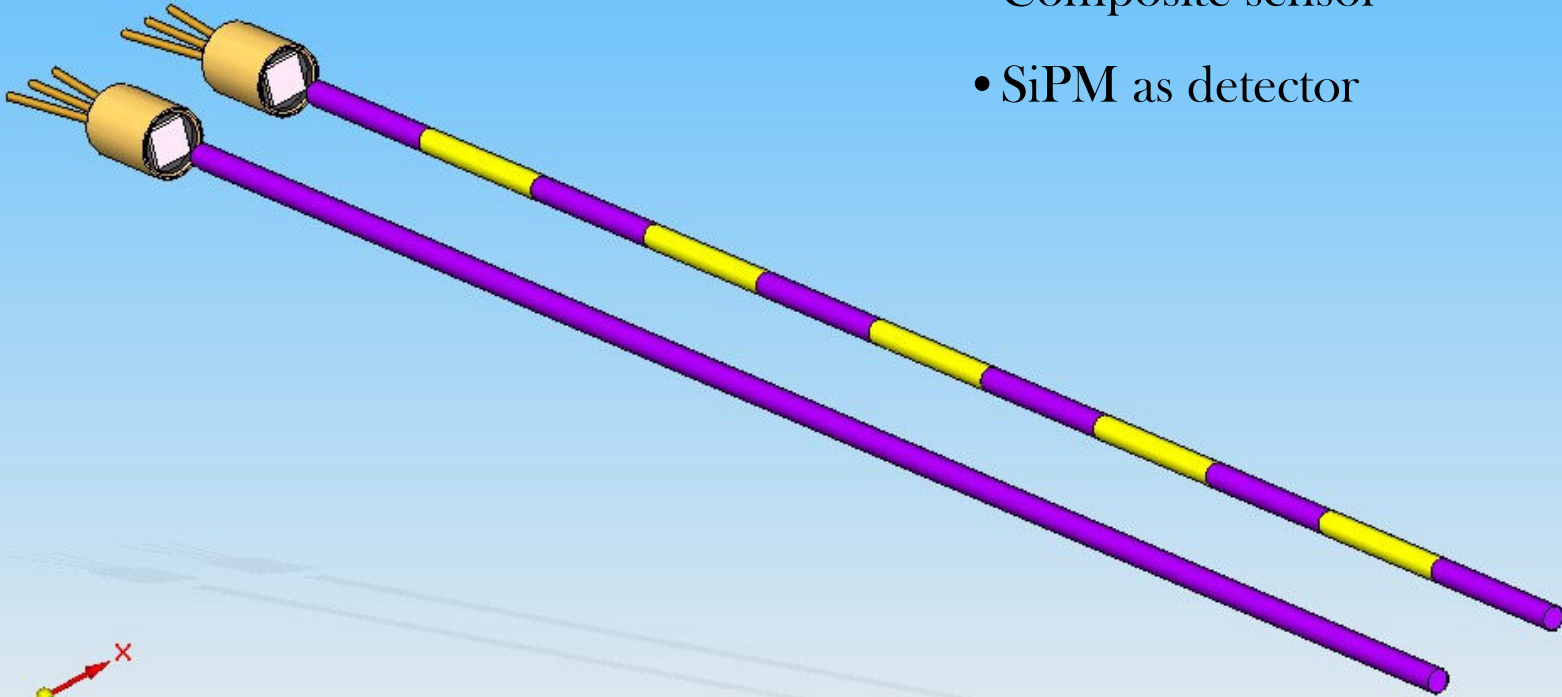
## Issues

(RIA)

	$E$ (GeV)	$e^-$ loss/ year	Consequence for electronics
<b>Main Beam</b>	1500	1 E14	Unacceptably high failure rate
<b>Main Beam</b>	9	1 E15	More failures per year
<b>Drive Beam</b>	2.4	1 E16	Few failures per year
<b>Drive Beam</b>	0.24	1 E17	Few failures over lifetime

# Working principles

- Composite sensor
- SiPM as detector





# Cerenkov effect in optical fiber: parameters

---

- Silica multimode fibers with high NA (about 0,63)
- Refractive index 1,46
- Cerenkov semiangle  $47^\circ$  for electrons
- Average number of photon produced for each electron about 450 between [400-600]nm
- Electron energy threshold for Cerenkov production 0,192 MeV
- High fibers lifetime and radiation hardness
- Smart structure

## Disadvantages

- Loss of particles with angles non included in the acceptance angle

## Improvements

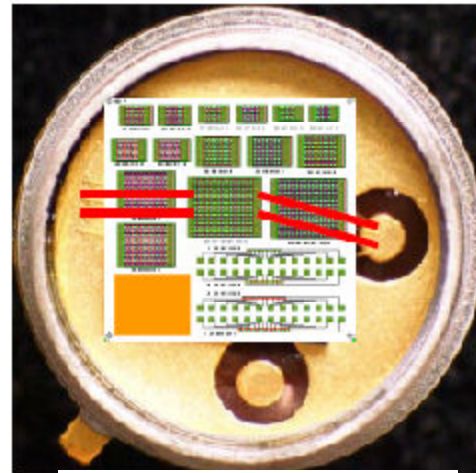
- Increase NA: Photonic bandgap fiber



# Photon detector: SiPM

In collaboration with STMicroelectronics-Catania

**Mod F**



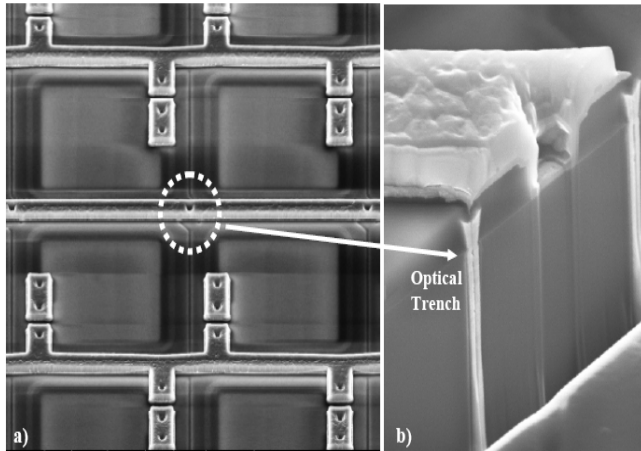
- Matrix of n pixels (SPAD) in parallel
- Every pixel gives the same signal when it is hit by a photon but the output charge is proportional to the number of triggered cells, i.e the number of injected photons:

$$Q_{\text{out}} = C(V_R - V_{BR}) N_{\text{fired}}$$

- Analog device
- Photon detection efficiency: ca 20% at 450 nm

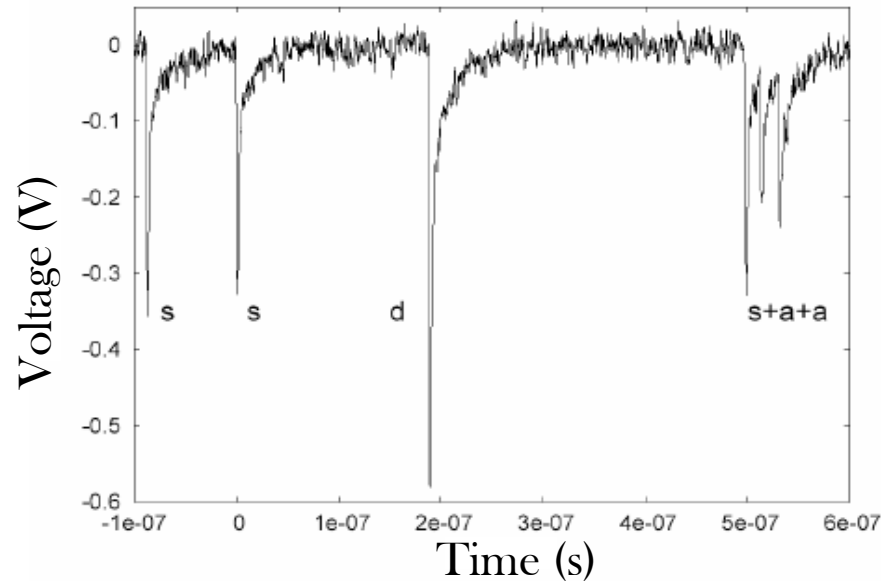
**Mod E**

Chip size: 4.37 x 4.37 mm  
 Array size: 1 x 1 mm  
 Cells array: 20 x 20  
 Cells Pitch: 50 μm  
 Cells fill factor: 36 %



Rise time: 1-2 ns

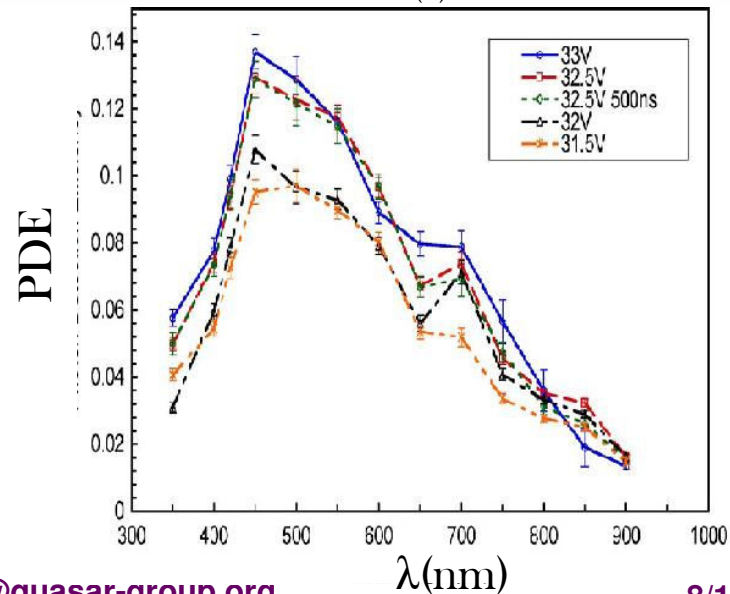
Recovery time:  
ca 20 ns  
(depending on  
the quenching  
circuitry)



## Photon Detection Efficiency

# Detected photons / # Incident photons

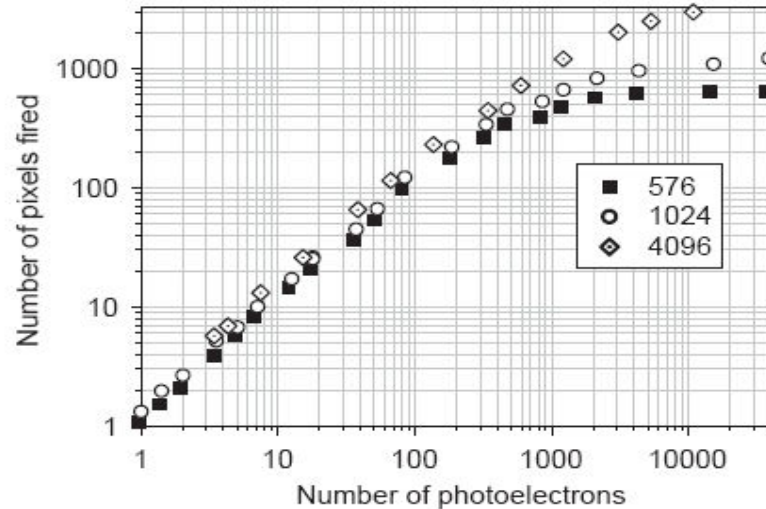
$$\eta_{SiPM} = \varepsilon_{geom} \times QE \times \varepsilon_{avalanche}$$





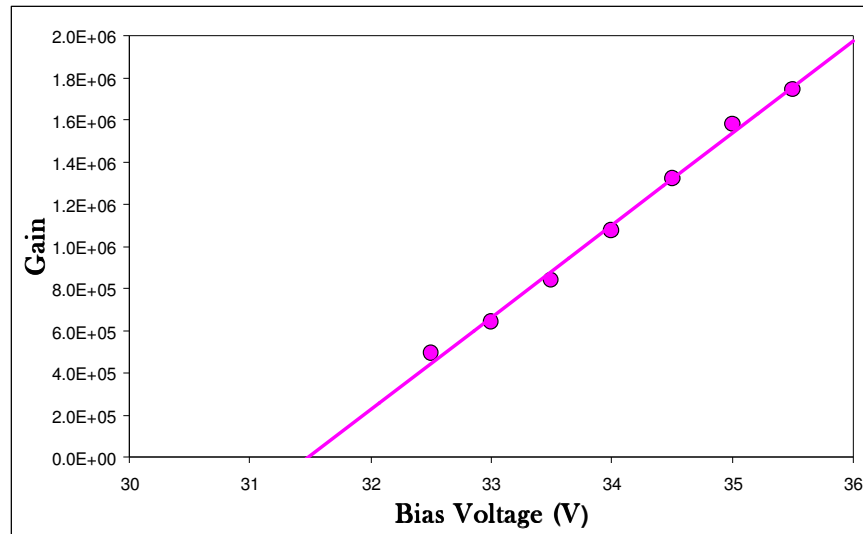
## Dynamic range

Best working condition  $\Rightarrow N_{\text{photons}} < N_{\text{cells}}$



## Gain linearity

- linear variable with  $V_{\text{bias}}$



- It seems possible to realize a sensor:
  - low cost
  - extremely compact
  - with a robust mechanical design
  - immune to external magnetic field
  - radiation hardness
- After the experimental test the **ST SiPMS** seems to be the best solution for this particular application
- Next steps:
  - sensor performances analysis
  - installation at Cern for measuring beam losses at Two Beam Test Area.



Thank you very much for your  
attention

